Author Index of Volume 232

Adams, H. P., 115
Agnihotri, O. P., 47
Ahn, B. T., 28
Akhsakhalyan, A. D., 252
Albu-Yaron, A., 208
Amm, D. T., 245
Aravot, Y. M., 208
Arvia, A. J., 63
Ashrit, P. V., 83

Baazi, T., 185
Bader, G., 83
Bah, K., 18
Bai, G., 34
Bai, H. Y., 282
Batzel, D. A., 110
Benkhelifa, F., 83
Bindal, A., 105
Bodnar, I. V., 139
Bonnett, R., 110
Braglia, M., 21
Brett, M. J., 228
Brynda, E., 120

Caccavale, F., 21
Chari, K. S., 47
Chen, H., 282
Chen, H. C., 161
Chen, J., 149
Chen, K., 237
Choi, C. K., 34
Chorkendorff, I., 215
Chuang, Y. C., 161
Chuang, G. Y., 28
Clark, T. R., 110
Clausen, T., 215
Cocito, G., 21
Croitour, N., 143
Czapla, A., 18

DeArmond, A. H., 115
DeArmond, M. K., 115
Delgass, W. N., 126
Djessas, K., 194
Donovan, K. J., 110
Du, W., 194
Dvorak, O., 115

Ehrhardt, H., 51

Falke, U., 154
Fan, W. L., 41
Franses, E. I., 126
Fuchs, A., 51
Fukuda, K., 180

Galli, C., 105
Gao, Y., 278
Girouard, F. E., 83
Gremenok, V. F., 139
Gu, Z.-N., 149
Gupta, S. K., 245

Han, A., 278
Heol, R. H., 73
Higuchi, H., 256
Howe, R. T., 1
Hsu, W. T., 41
Hultman, L., 169

Im, H. B., 28
Imai, Y., 180

Jin, D., 261
Jin, Z.-X., 149
Johnson, D. J., 245
Jugduth, H. K., 126
Jung, K., 51

Kaiser, N., 16
Kaiser, U., 16
Kalvoda, L., 120
Kameyama, T., 180
Kawai, K., 271
Kenney, M. E., 110
Kim, H. D., 28
Kim, K. H., 34
Kim, S. C., 34
Knystautas, E. J., 185
Konevecki, M. W., 228
Kornelson, K. E., 228
Kouyama, T., 271
Kovalchuk, M. V., 252
Kubono, A., 256
Kumar, V., 47
Kwok, H. S., 99

Lai, R., 265
Laor, A., 143
Larsen, J., 215
Laursen, T., 245
Lee, J. J., 34
Lee, J. Y., 34
Leistiko, O., 215
Li, C.-Y., 149
Lin, Y., 278
Liu, S., 237
Liu, Z. Y., 161
Luo, K.-J., 149

Magomedov, M. A., 139
Malysheva, N. E., 252
Marshbanks, T. L., 126
Maruyama, T., 201
Massé, G., 194
Monk, D. J., 1
Mukaida, M., 180
Müller, S., 232

Nam, S. T., 34
Nicolet, M.-A., 34
Novikova, N. N., 252

Ogura, S., 105
Okui, N., 256
Omichi, H., 13
Osato, K., 180

Paradiso, R., 110
Pécz, B., 68
Pelleg, J., 143
Perdriel, C., 63
Pisarkiewicz, T., 18
Platonov, Yu. Ya., 252

Radhakrishnan, K., 94
Radnóczi, G., 68
Ranta-aho, T., 56
Restivo, J., 105
Rigato, V., 21
Rovedo, N., 105
Rud', Yu. V., 139

Salashchenko, N. N., 252
Scharff, 154
Scherer, J., 51
Schröer, A., 154
Scott, K., 110
Sessa, V., 21
Shih, H. C., 41
Simanovskis, A., 87
Sjöström, H., 169
Soane, D. S., 1
Soon, F. Y., 94
Sosphenov, A. N., 252
Stolyarova, S. V., 87
Sudiwala, R. V., 110
Sullivan, B. T., 228
Sundgren, J.-E., 169
Sung, C. P., 41

Tago, T., 201
Tamada, M., 13
Terranova, M. L., 21
Topkar, A., 265
Truong, V.-V., 83

Uehara, K., 271
Ullmann, J., 154
Umemoto, S., 256

Vuorinen, S., 73

Wallenberg, L. R., 169
Wang, F., 232
Wang, W. H., 282
Wang, W. K., 282
Watanabe, A., 180
Westra, K. L., 228
Wilkins, R. F., 110
Wilson, E. G., 110
Wolf, G. K., 154
Wördenweber, R., 232

Xiao, Y., 261
Xu, L. K., 161

Yan, P., 204
Yang, S. Z., 204
Yao, Z., 261
Ye, Z.-Y., 149
Yin, D.-L., 149
Ylilammi, M., 56

Zaretskaya, E. P., 139
Zerbino, J. O., 63
Zevin, L., 143
Zhang, J., 278
Zhang, J.-L., 149
Zhang, X., 237
Zhang, X.-D., 149
Zhang, Y., 282
Zhao, W.-B., 149
Zhao, Y., 278
Zheludeva, S. I., 252
Zheng, J. P., 99
Zhou, X.-H., 149
Zuber, A., 16

Subject Index of Volume 232

Adhesion
ageing effects in Me/TlBr–TlI systems, 87
iron phosphate coatings on cold-rolled steel: morphology formation and intrinsic adhesion mechanisms, 208
Ageing
ageing effects in Me/TlBr–TlI systems, 87
Amorphization
structural and electrical properties of $^{28}Si^{+}$ and $^{40}Ar^{+}$ ion implanted epitaxial $ReSi_2$ films grown on n-Si(100) substrates, 34
study of the structure of sputter-deposited Ni–Si multilayers, 282
Amorphous materials
crystallization of encapsulated very thin amorphous Ge layers, 68
microstructure of amorphous C:H and metal-containing C:H films deposited on steel substrates, 169
noble gas ion assisted evaporation of carbon, 154
Anisotropy
anisotropy in residual strains and the lattice parameter of reactive sputter-deposited ZrN films, 143
determination of anisotropic electron transport properties of two Langmuir–Blodgett organic multiple quantum wells, 110
Auger electron spectroscopy
ageing effects in Me/TlBr–TlI systems, 87
determination of sp^2/sp^3 carbon bonding ratio in a-C:H including irradiation damage by factor analysis of Auger electron spectra, 51
transport properties of low-resistance ohmic contacts to InP, 215

Biomaterials
photoelectric response of oriented purple membrane electrodeposited onto poly(vinyl alcohol) film, 271
Boron nitride
hexagonal boron nitride synthesis by nitrogen ion implantation of boron films, 185

Cadmium sulphide
properties of CdS films prepared by the chemical mist deposition process, 28
Carbon
determination of sp^2/sp^3 carbon bonding ratio in a-C:H including irradiation damage by factor analysis of Auger electron spectra, 51
microstructure of amorphous C:H and metal-containing C:H films deposited on steel substrates, 169
noble gas ion assisted evaporation of carbon, 154
Carboxylic acids
structure and composition of LB films of cadmium stearate by FTIR spectroscopy and XPS, 126
Chemical vapour deposition
characterization of Cu(Ga, In)Se_2 thin films and heterojunctions grown by close-spaced vapour transport, 194
densification of Ta_2O_5 film prepared by KrF excimer laser CVD, 180
growth and morphological changes of chemically vapour deposited diamond in the presence of argon, 41
interfacial characterization of chemically vapour deposited titanium carbide on cemented carbide, 73
optical determination of the film thicknesses in multilayer thin film structures, 56
silicon dioxide thin films prepared by photochemical vapor deposition from silicon tetraacetate, 201
silicon oxynitride films deposited by mercury photosensitization chemical vapour deposition, 47
time-dependent evolution of the structure and chemical bonds in diamond-like carbon films generated by the hot filament chemical vapour deposition method, 21
Clusters
growth and structure of C_{60} thin films on NaCl, glass and mica substrates, 149
Coatings
anisotropy in residual strains and the lattice parameter of reactive sputter-deposited ZrN films, 143
iron phosphate coatings on cold-rolled steel: morphology formation and intrinsic adhesion mechanisms, 208
Computer simulation
structure and morphology of copper tetra-tert-butylphthalocyanine Langmuir–Blodgett films, 120
Conductivity
highly conducting Langmuir–Blodgett film, 261
properties of CdS films prepared by the chemical mist deposition process, 28
Corrosion
corrosion behavior of various TiN thin films produced by ion mixing and PVD methods, 204
iron phosphate coatings on cold-rolled steel: morphology formation and intrinsic adhesion mechanisms, 208

Deposition process
properties of CdS films prepared by the chemical mist deposition process, 28
study of electrodeposited GaAs films, 278
study of the structure of sputter-deposited Ni–Si multilayers, 282
Diamond
growth and morphological changes of chemically vapour deposited diamond in the presence of argon, 41

Electrical properties and measurements
determination of anisotropic electron transport properties of two Langmuir–Blodgett organic multiple quantum wells, 110
highly conducting Langmuir–Blodgett film, 261
near room temperature deposited indium tin oxide films as transparent conductors and counterelectrodes in electrochromic systems, 83
on factors influencing Si segregation and its effect on the two-dimensional electron gas mobility in inverted GaAs/n-AlGaAs heterostructures, 94
photosensitivity of In–p-CuIn$_x$Ga$_{1-x}$Se$_2$ thin film structures, 139
transport properties of low-resistance ohmic contacts to InP, 215
Electrochemistry
ellipsometry of hydrous platinum oxide layers and electrodispersed platinum surfaces resulting from their electroreduction, 63

transmission electron microscopy of stearic acid Langmuir–Blodgett films with incorporated ruthenium(II)tris(2,2′-bipyridyl) complex, 115
Ellipsometry
ellipsometry of hydrous platinum oxide layers and electrodispersed platinum surfaces resulting from their electroreduction, 63
Epitaxy
growth and structure of C_{60} thin films on NaCl, glass and mica substrates, 149
interfacial characterization of chemically vapour deposited titanium carbide on cemented carbide, 73
large-area epitaxial MgO buffer layers on sapphire substrates for Y–Ba–Cu–O film deposition, 232
Etching
review of the chemical reaction mechanism and kinetics for hydrofluoric acid etching of silicon dioxide for surface micromachining applications, 1

Faceting
growth and morphological changes of chemically vapour deposited diamond in the presence of argon, 41
Factor analysis
determination of sp^2/sp^3 carbon bonding ratio in a-C:H including irradiation damage by factor analysis of Auger electron spectra, 51
Fluorescence
new modification of X-ray standing waves above the surface of layered substrates under total external reflection conditions for structural characterization of organic layers, 252
Fluorine
review of the chemical reaction mechanism and kinetics for hydrofluoric acid etching of silicon dioxide for surface micromachining applications, 1
Fourier transform infrared spectroscopy
direct formation of polyimide thin films by vapor deposition polymerization, 256
structure and composition of LB films of cadmium stearate by FTIR spectroscopy and XPS, 126

Gallium arsenide
study of electrodeposited GaAs films, 278
Germanium
crystallization of encapsulated very thin amorphous Ge layers, 68
Growth mechanism
growth and structure of C_{60} thin films on NaCl, glass and mica substrates, 149
noble gas ion assisted evaporation of carbon, 154

Hardness
silicon dioxide thin films prepared by photochemical vapor deposition from silicon tetraacetate, 201

Indium oxide
near room temperature deposited indium tin oxide films as transparent conductors and counterelectrodes in electrochromic systems, 83
preparation of indium tin oxide films at room temperature by pulsed laser deposition, 99
Indium phosphide
transport properties of low-resistance ohmic contacts to InP, 215
Infrared spectroscopy
hexagonal boron nitride synthesis by nitrogen ion implantation of boron films, 185
silicon dioxide thin films prepared by photochemical vapor deposition from silicon tetraacetate, 201
Insulators
effect of electrolyte exposure on silicon dioxide in electrolyte–oxide–semiconductor structures, 265
Interfaces
crystallization of encapsulated very thin amorphous Ge layers, 68
effect of electrolyte exposure on silicon dioxide in electrolyte–oxide–semiconductor structures, 265
transport properties of low-resistance ohmic contacts to InP, 215
Iodine
fabrication of extremely thin silicon on insulator for fully-depleted CMOS applications, 105
Ion bombardment
noble gas ion assisted evaporation of carbon, 154
Ion implantation
corrosion behavior of various TiN thin films produced by ion mixing and PVD methods, 204
hexagonal boron nitride synthesis by nitrogen ion implantation of boron films, 185
structural and electrical properties of $^{28}Si^+$ and $^{40}Ar^+$ ion implanted epitaxial $ReSi_2$ films grown on n-Si(100) substrates, 34

Langmuir–Blodgett films
determination of anisotropic electron transport properties of two Langmuir–Blodgett organic multiple quantum wells, 110
highly conducting Langmuir–Blodgett film, 261
Langmuir–Blodgett deposition of yttrium arachidate, 245
new modification of X-ray standing waves above the surface of layered substrates under total external reflection conditions for structural characterization of organic layers, 252
structure and composition of LB films of cadmium stearate by FTIR spectroscopy and XPS, 126
structure and morphology of copper tetra-tert-butylphthalocyanine Langmuir–Blodgett films, 120
third-order optical non-linearity of absorbing dye Langmuir–Blodgett films, 237
transmission electron microscopy of stearic acid Langmuir–Blodgett films with incorporated ruthenium(II)tris(2,2′-bipyridyl) complex, 115
Laser ablation
photosensitivity of In–p-$CuIn_xGa_{1-x}Se_2$ thin film structures, 139
preparation of indium tin oxide films at room temperature by pulsed laser deposition, 99
Laser irradiation
densification of Ta_2O_5 film prepared by KrF excimer laser CVD, 180

Mercury
silicon oxynitride films deposited by mercury photosensitization chemical vapour deposition, 47
Metal–oxide semiconductor structures
effect of electrolyte exposure on silicon dioxide in electrolyte–oxide–semidonductor structures, 265
Metal–oxide structure
ellipsometry of hydrous platinum oxide layers and electrodispersed platinum surfaces resulting from their electroreduction, 63

Metals
microstructure of amorphous C:H and metal-containing C:H films deposited on steel substrates, 169
Methane
growth and morphological changes of chemically vapour deposited diamond in the presence of argon, 41
Molecular beam epitaxy
on factors influencing Si segregation and its effect on the two-dimensional electron gas mobility in inverted GaAs/n-AlGaAs heterostructures, 94
Multilayers
optical determination of the film thicknesses in multilayer thin film structures, 56
photoelectric response of oriented purple membrane electrodeposited onto poly(vinyl alcohol) film, 271
study of the structure of sputter-deposited Ni–Si multilayers, 282
third-order optical non-linearity of absorbing dye Langmuir–Blodgett films, 237

Nitrides
anisotropy in residual strains and the lattice parameter of reactive sputter-deposited ZrN films, 143
optical constants of reactively-sputtered NbN films, 228

Optical properties
near room temperature deposited indium tin oxide films as transparent conductors and counterelectrodes in electrochromic systems, 83
optical constants of reactively-sputtered NbN films, 228
optical determination of the film thicknesses in multilayer thin film structures, 56
properties of CdS films prepared by the chemical mist deposition process, 28
third-order optical non-linearity of absorbing dye Langmuir–Blodgett films, 237
Optical spectroscopy
optical determination of the film thicknesses in multilayer thin film structures, 56
Oxides
large-area epitaxial MgO buffer layers on sapphire substrates for Y–Ba–Cu–O film deposition, 232
structure of plasma-deposited ZrO_2–Y_2O_3 ceramic layers, 161
Oxygen
fabrication of extremely thin silicon on insulator for fully-depleted CMOS applications, 105

Photoconductivity
determination of anisotropic electron transport properties of two Langmuir–Blodgett organic multiple quantum wells, 110
Photovoltage
photoelectric response of oriented purple membrane electrodeposited onto poly(vinyl alcohol) film, 271
study of electrodeposited GaAs films, 278
Physical vapour deposition
corrosion behavior of various TiN thin films produced by ion mixing and PVD methods, 204
direct formation of polyimide thin films by vapor deposition polymerization, 256
Plasma processing and deposition
structure of plasma-deposited ZrO_2–Y_2O_3 ceramic layers, 161
Platinum
ellipsometry of hydrous platinum oxide layers and electrodispersed platinum surfaces resulting from their electroreduction, 63

Polymers
direct formation of polyimide thin films by vapor deposition polymerization, 256

Radiation damage
determination of sp^2/sp^3 carbon bonding ratio in a-C:H including irradiation damage by factor analysis of Auger electron spectra, 51
Reaction kinetics
time-dependent evolution of the structure and chemical bonds in diamond-like carbon films generated by the hot filament chemical vapour deposition method, 21
Resistivity
ageing effects in Me/TlBr–TlI systems, 87
preparation of indium tin oxide films at room temperature by pulsed laser deposition, 99
Rhenium
structural and electrical properties of $^{28}Si^+$ and $^{40}Ar^+$ ion implanted epitaxial $ReSi_2$ films grown on n-Si(100) substrates, 34
Ruthenium
transmission electron microscopy of stearic acid Langmuir–Blodgett films with incorporated ruthenium(II)tris(2,2′-bipyridyl) complex, 115
Rutherford backscattering spectroscopy
Langmuir–Blodgett deposition of yttrium arachidate, 245

Scanning electron microscopy
characterization of Cu(Ga, In)Se_2 thin films and heterojunctions grown by close-spaced vapour transport, 194
Schottky barrier
photosensitivity of In–p-$CuIn_xGa_{1-x}Se_2$ thin film structures, 139
Segregation
on factors influencing Si segregation and its effect on the two-dimensional electron gas mobility in inverted GaAs/n-AlGaAs heterostructures, 94
Selenides
characterization of Cu(Ga, In)Se_2 thin films and heterojunctions grown by close-spaced vapour transport, 194
Semiconductors
highly conducting Langmuir–Blodgett film, 261
Sensors
effect of electrolyte exposure on silicon dioxide in electrolyte–oxide–semiconductor structures, 265
photoelectric response of oriented purple membrane electrodeposited onto poly(vinyl alcohol) film, 271
Silicides
structural and electrical properties of $^{28}Si^+$ and $^{40}Ar^+$ ion implanted epitaxial $ReSi_2$ films grown on n-Si(100) substrates, 34
Silicon
fabrication of extremely thin silicon on insulator for fully-depleted CMOS applications, 105
review of the chemical reaction mechanism and kinetics for hydrofluoric acid etching of silicon dioxide for surface micromachining applications, 1
Silicon nitride
silicon oxynitride films deposited by mercury photosensitization chemical vapour deposition, 47
Silicon oxide
effect of electrolyte exposure on silicon dioxide in electrolyte–oxide–semiconductor structures, 265

review of the chemical reaction mechanism and kinetics for hydrofluoric acid etching of silicon dioxide for surface micromachining applications, 1
silicon dioxide thin films prepared by photochemical vapor deposition from silicon tetraacetate, 201
silicon oxynitride films deposited by mercury photosensitization chemical vapour deposition, 47
Sputtering
large-area epitaxial MgO buffer layers on sapphire substrates for Y–Ba–Cu–O film deposition, 232
optical constants of reactively-sputtered NbN films, 228
Steel
iron phosphate coatings on cold-rolled steel: morphology formation and intrinsic adhesion mechanisms, 208
microstructure of amorphous C:H and metal-containing C:H films deposited on steel substrates, 169
Structural properties
new modification of X-ray standing waves above the surface of layered substrates under total external reflection conditions for structural characterization of organic layers, 252
photosensitivity of In–p-$CuIn_xGa_{1-x}Se_2$ thin film structures, 139
structure and morphology of copper tetra-tert-butylphthalocyanine Langmuir–Blodgett films, 120
time-dependent evolution of the structure and chemical bonds in diamond-like carbon generated by the hot filament chemical vapour deposition method, 21
Sulphur
fabrication of extremely thin silicon on insulator for fully-depleted CMOS applications, 105
Superconductivity
large-area epitaxial MgO buffer layers on sapphire substrates for Y–Ba–Cu–O film deposition, 232
optical constants of reactively-sputtered NbN films, 228
Surface segregation
on factors influencing Si segregation and its effect on the two-dimensional electron gas mobility in inverted GaAs/n-AlGaAs heterostructures, 94

Tantalum
densification of Ta_2O_5 film prepared by KrF excimer laser CVD, 180
Thallium
ageing effects in Me/TlBr–TlI systems, 87
Tin
preparation of indium tin oxide films at room temperature by pulsed laser deposition, 99
Tin oxide
near room temperature deposited indium tin oxide films as transparent conductors and counterelectrodes in electrochromic systems, 83
Titanium carbide
interfacial characterization of chemically vapour deposited titanium carbide on cemented carbide, 73
Titanium nitride
corrosion behavior of various TiN thin films produced by ion mixing and PVD methods, 204
Transmission electron microscopy
crystallization of encapsulated very thin amorphous Ge layers, 68
growth and structure of C_{60} thin films on NaCl, glass and mica substrates, 149
interfacial characterization of chemically vapour deposited titanium carbide on cemented carbide, 73
structure of plasma-deposited ZrO_2–Y_2O_3 ceramic layers, 161
transmission electron microscopy of stearic acid Langmuir–Blodgett films with incorporated rethenium(II)tris(2,2′-bipyridyl) complex, 115

X-ray diffraction
characterization of Cu(Ga, In)Se_2 thin films and heterojunctions grown by close-spaced vapour transport, 194
direct formation of polyimide thin films by vapor deposition polymerization, 256
structure and morphology of copper tetra-tert-butylphthalocyanine Langmuir–Blodgett films, 120
study of electrodeposited GaAs films, 278
study of the structure of sputter-deposited Ni–Si multilayers, 282
X-ray photoelectron spectroscopy
hexagonal boron nitride synthesis by nitrogen ion implantation of boron films, 185
Langmuir–Blodgett deposition of yttrium arachidate, 245
structure and composition of LB films of cadmium stearate by FTIR spectroscopy and XPS, 126
X-ray scattering
anisotropy in residual strains and the lattice parameter of reactive sputter-deposited ZrN films, 143
X-ray total reflection analysis
new modification of X-ray standing waves above the surface of layered substrates under total external reflection conditions for structural characterization of organic layers, 252

Yttrium
Langmuir–Blodgett deposition of yttrium arachidate, 245

Zirconium
structure of plasma-deposited ZrO_2–Y_2O_3 ceramic layers, 161